

S1NB80

800V 1A

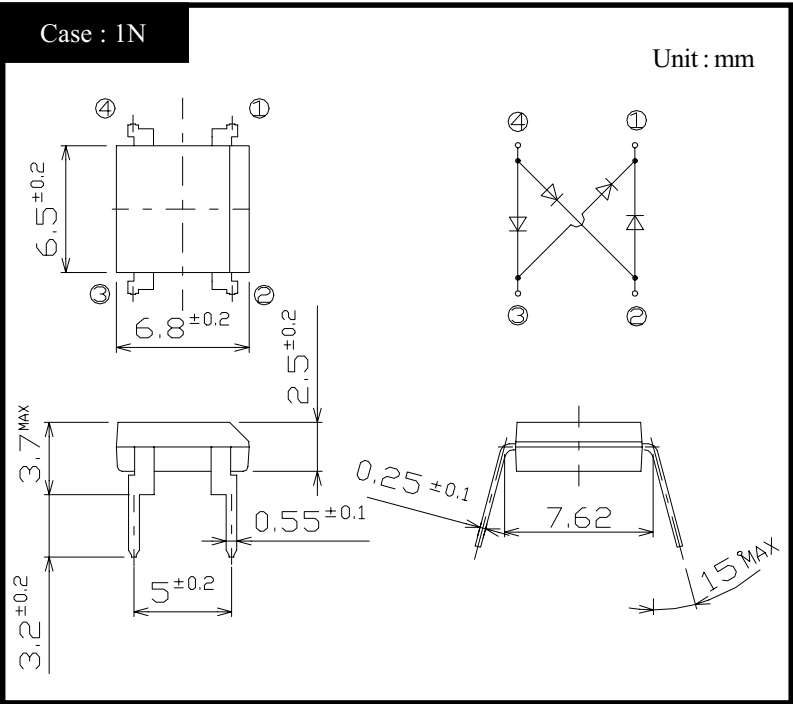
FEATURES

- Small Dual In-Line(:DIL) Package
- 5 mm pitch between terminals
- Applicable to Automatic Insertion

APPLICATION

- Switching power supply
- Home Appliances, Office Equipment
- Telecommuication, Factory Automation

OUTLINE DIMENSIONS



RATINGS

●Absolute Maximum Ratings (If not specified TI=25°C)

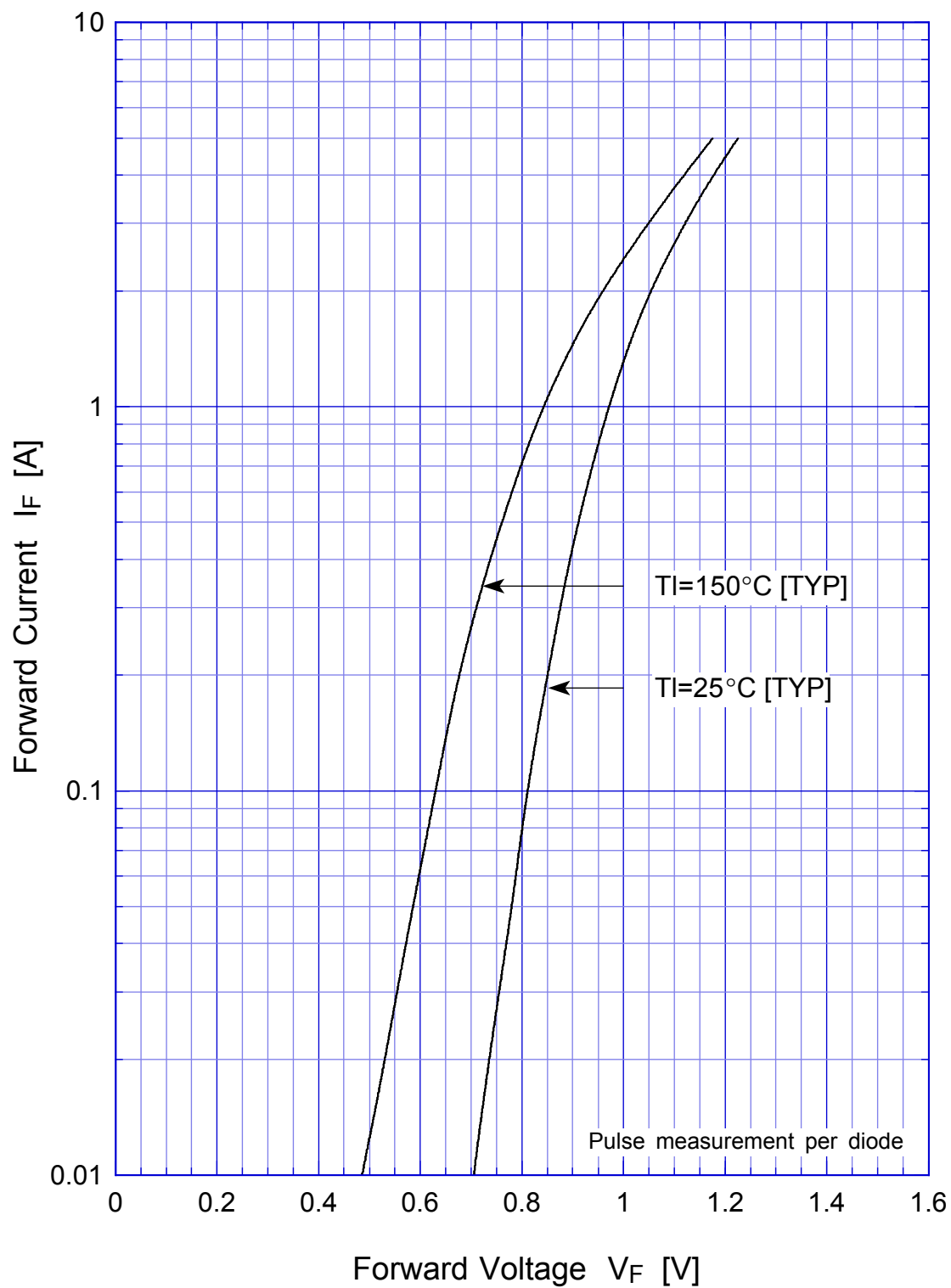
Item	Symbol	Conditions	Ratings	Unit
Storage Temperature	T _{stg}		-40~150	°C
Operating Junction Temperature	T _j		150	°C
Maximum Reverse Voltage	V _{RM}		800	V
Average Rectified Forward Current	I _O	50Hz sine wave, R-load, On glass-epoxy substrate, T _a =25°C	1	A
Peak Surge Forward Current	I _{FSM}	50Hz sine wave, Non-repetitive 1 cycle peak value, T _j =25°C	30	A
Current Squared Time	I ² t	1ms≤t<10ms T _j =25°C	4.5	A ² s

●Electrical Characteristics (If not specified TI=25°C)

Item	Symbol	Conditions	Ratings	Unit
Forward Voltage	V _F	I _F =0.5A, Pulse measurement, Rating of per diode	Max.1.05	V
Reverse Current	I _R	V _R =V _{RM} , Pulse measurement, Rating of per diode	Max.10	μA
Thermal Resistance	θ _{jl}	junction to lead	Max.15	°C/W
	θ _{ja}	junction to ambient	Max.68	

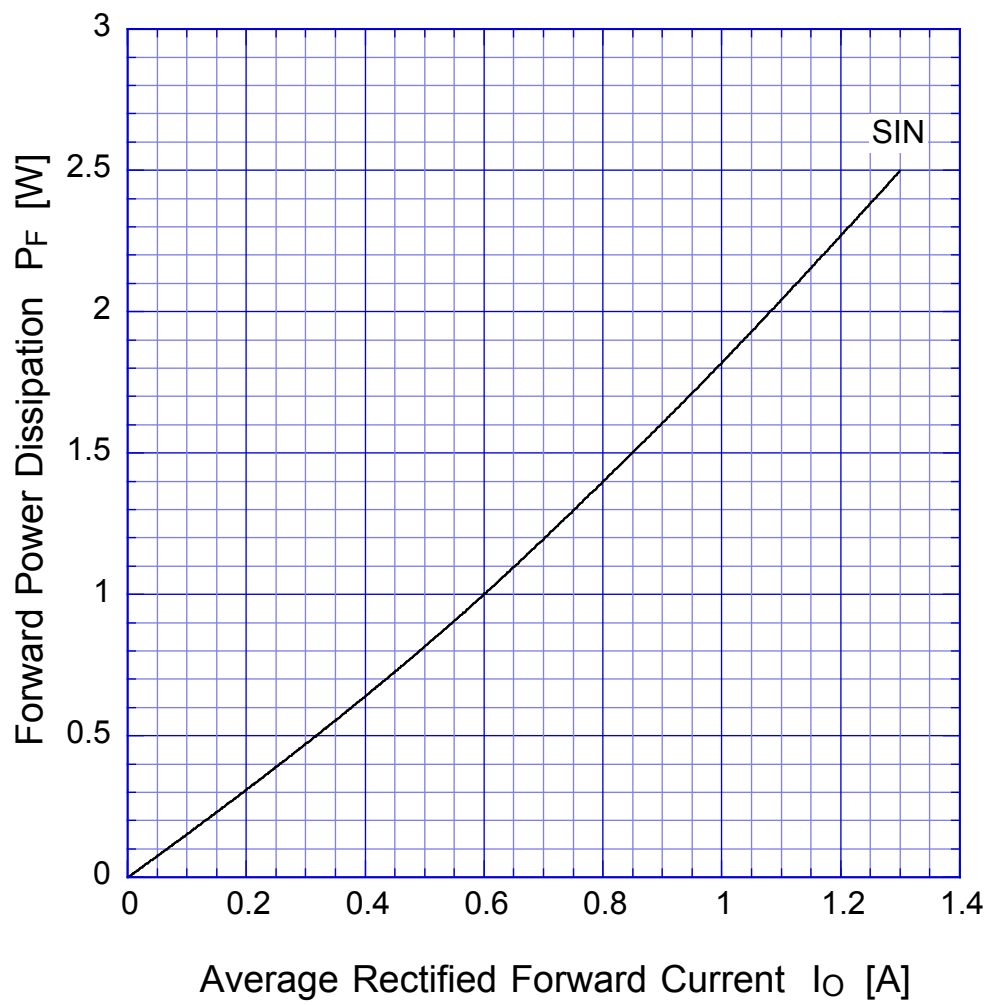
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Forward Voltage



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Forward Power Dissipation

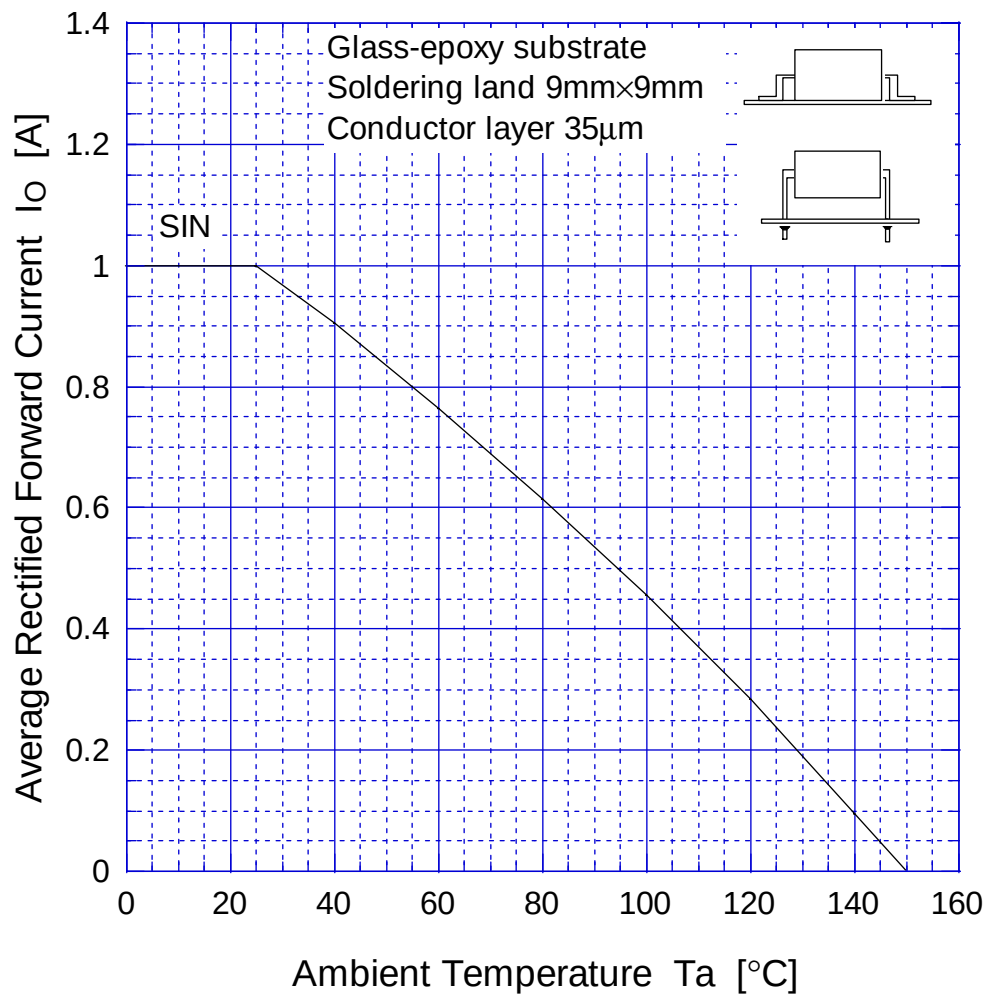


$T_j = 150^\circ\text{C}$

Sine wave

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Derating Curve



Sine wave
R-load
Free in air

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Peak Surge Forward Capability

